## STMUX1800L

## 16- to 8-bit MUX/DEMUX for gigabit Ethernet LAN switch with LED switch and enhanced ESD protection

## Features

- Low $\mathrm{R}_{\mathrm{ON}}: 4.0 \Omega$ typical

■ $\mathrm{V}_{\mathrm{CC}}$ operating range: 3.0 to 3.6 V
■ Enhanced ESD protection: $>8 \mathrm{kV}$ (contact) and 15 kV (HBM)
■ Channel on capacitance: 9.5 pF typical

- Switching time speed: 9 ns

■ Near to zero propagation delay: 250 ps
■ Very low crosstalk: -45 dB at 250 MHz
■ Bit-to-bit skew: 200 ps
■ $>600 \mathrm{MHz}-3 \mathrm{~dB}$ typical bandwidth (or data frequency)

■ Three SPDT switches for LED support

- Rail-to-rail switching on data I/O ports (0 V to 5 V )
■ Package: QFN56
- Pb-free


## Applications

- $10 / 100 / 1000$ Mbit Ethernet switching

■ Audio/video switching


## Description

The STMUX1800L is a 16 - to 8 -bit multiplexer/demultiplexer low $\mathrm{R}_{\mathrm{ON}}$ bidirectional LAN switch designed for various standards, such as 10/100/1000 Ethernet. It is designed for very low crosstalk, low bit-to-bit skew and low I/O capacitance.
The differential signal from the Gigabit Ethernet transceiver is multiplexed into one of two selected outputs while the unselected switch goes to Hi-Z status.

The device integrates three SPDT (single pole dual throw) switches, for LED support.

Table 1. Device summary

| Order code | Package | Packing |
| :---: | :---: | :---: |
| STMUX1800LQTR | QFN56 | Tape and reel |

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## 1 <br> Pin description

Figure 1. Pin connection (top through view)


Table 2. Pin description

| Pin | Symbol | Name and function |
| :---: | :---: | :--- |
| $2,3,7,8,11,12,14,15$ | A, B, C, D, E, F, G, H | 8-bit bus |
| $48,47,43,42,37,36,32,31$ | A0, B0, C0, D0, E0, F0, G0, H0 | 8-bit multiplexed to bus 0 |
| $46,45,41,40,35,34,30,29$ | A1, B1, C1, D1, E1, F1, G1, H1 | 8-bit multiplexed to bus 1 |
| 5 | N/C | Not connected |
| 17 | SEL | Bus and LED switch selection |
| $19,20,54$ | LED1, LED2, LED3 | LED switch input |
| $22,23,25,26,51,52$ | LED1_0, LED2_0, LED1_1, <br> LED2_1, LED3_1, LED3_0 | LED switch output |
| $4,10,18,27,38,50,56$ | VDD | Supply voltage |
| $1,6,9,13,16,21,24,28,33$, | GND | Ground |
| $39,44,49,53,55$ |  |  |

Figure 2. Input equivalent circuit


Table 3. LAN switch function table

| SEL | Function |
| :---: | :--- |
| L | 8-bit bus to 8-bit multiplexed bus 0 |
| H | 8-bit bus to 8-bit multiplexed bus 1 |

Table 4. LED switch function table

| SEL | Function |
| :---: | :--- |
| L | LED switch input connected to LED switch output X_0 |
| $H$ | LED switch input connected to LED switch output X_1 |

## 2 Maximum ratings

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 5. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage to ground | -0.5 to 4.6 | V |
| $\mathrm{~V}_{\mathrm{IO}}$ | DC input output voltage | -0.5 to 4.6 | V |
| $\mathrm{~V}_{\mathrm{IC}}$ | DC control input voltage | -0.5 to 4.6 | V |
| $\mathrm{I}_{\mathrm{O}}$ | DC output current ${ }^{(1)}$ | 120 | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power dissipation | 0.5 | W |
| $\mathrm{~T}_{\text {stg }}$ | Storage temperature | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead temperature (10 sec) | 300 | ${ }^{\circ} \mathrm{C}$ |

1. If $\mathrm{V}_{\mathrm{IO}} \times \mathrm{I}_{\mathrm{O}}$ does not exceed the maximum limit of $\mathrm{P}_{\mathrm{D}}$.

### 2.1 Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Value |  |  | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage to ground | 3 | - |  | V |
| $\mathrm{~V}_{\mathrm{IC}}$ | DC control input voltage (SEL) | 0 | - | 5 | V |
| $\mathrm{~V}_{\mathrm{IO}}$ | DC input/output voltage | 0 | - | $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\mathrm{A}}$ | Operating temperature | -40 | - | 85 | ${ }^{\circ} \mathrm{C}$ |

## 3 Electrical characteristics

Table 7. DC electrical characteristics for Gigabit Ethernet LAN8/16MUX/DEMUX
( $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Voltage input high (SEL) | High level guaranteed | 2 | - | - | V |
| $\mathrm{V}_{\text {IL }}$ | Voltage input low (SEL) | Low level guaranteed | -0.5 | - | 0.8 | V |
| $\mathrm{V}_{\mathrm{IK}}$ | Clamp diode voltage (SEL) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{IN}}=-18 \mathrm{~mA} \end{aligned}$ | - | -0.8 | -1.2 | V |
| $\mathrm{I}_{\mathrm{H}}$ | Input high current (SEL) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | - | - | $\pm 5$ | $\mu \mathrm{A}$ |
| $I_{\text {IL }}$ | Input low current (SEL) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{GND} \end{aligned}$ | - | - | $\pm 5$ | $\mu \mathrm{A}$ |
| $\mathrm{IOFF}_{(\mathrm{SW})}{ }^{(1)}$ | Leakage current through the switch common terminals ( A to H ) (LED1 to LED3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~A} \text { to } \mathrm{H}=\mathrm{V}_{\mathrm{CC}} \\ & \text { LED1 to } \mathrm{LED} 3=\mathrm{V}_{\mathrm{CC}} \\ & \text { A0 to } \mathrm{H} 0=0 \mathrm{~V} \\ & \text { A1 to } \mathrm{H} 1=\text { floating } \\ & \text { LEDx_0 }=0 \mathrm{~V} \\ & \text { LEDx1 = floating } \\ & \text { SEL }=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{IOFF}_{(\mathrm{SEL})}$ | SEL pin leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V} \\ & \mathrm{SEL}=0 \text { to } 3.6 \mathrm{~V} \end{aligned}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\mathrm{ON}}$ | Switch ON resistance ${ }^{(2)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=1.5 \text { to } \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ | - | 4.0 | 6.5 | $\Omega$ |
| $\mathrm{R}_{\text {FLat }}$ | ON resistance flatness (2) (3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}} \text { at } 1.5 \text { and } \mathrm{VCC} \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ | - | 0.5 | - | $\Omega$ |
| $\Delta \mathrm{R}_{\mathrm{ON}}$ | ON resistance match between channel $\underset{(2)(4)}{\Delta \mathrm{R}_{\mathrm{ON}}}=\mathrm{R}_{\mathrm{ONMAX}}-\mathrm{R}_{\mathrm{ONMIN}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=1.5 \text { to } \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{IN}}=-40 \mathrm{~mA} \end{aligned}$ | - | 0.4 | 1 | $\Omega$ |

1. Refer to Figure 4: Test circuit for leakage current (IOFF) on page 11
2. Measured by voltage drop between channels at indicated current through the switch. ON resistance is determined by the lower of the voltages.
3. Flatness is defined as the difference between the $R_{\text {ONMAX }}$ and $R_{\text {ONMIN }}$ of $O N$ resistance over the specified range.
4. $\Delta R_{\mathrm{ON}}$ measured at same $\mathrm{V}_{\mathrm{CC}}$, temperature and voltage level.

Table 8. DC electrical characteristics for 10/100 Ethernet LAN8/16MUX/DEMUX ( $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 10$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Voltage input high (SEL) | High level guaranteed | 2 | - | - | V |
| $\mathrm{V}_{\text {IL }}$ | Voltage input low (SEL) | Low level guaranteed | -0.5 | - | 0.8 | V |
| $\mathrm{V}_{\mathrm{IK}}$ | Clamp diode voltage (SEL) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{IN}}=-18 \mathrm{~mA} \end{aligned}$ | - | -0.7 | -1.2 | V |
| $\mathrm{I}_{\mathrm{H}}$ | Input high current (SEL) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | - | - | $\pm 5$ | $\mu \mathrm{A}$ |
| IIL | Input low current (SEL) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{GND} \end{aligned}$ | - | - | $\pm 5$ | $\mu \mathrm{A}$ |
| $\mathrm{IOFF}_{(\mathrm{SW})}{ }^{(1)}$ | Leakage current through the switch common terminals (A to H) <br> (LED1 to LED3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V} \\ & \mathrm{~A} \text { to } \mathrm{H}=\mathrm{V}_{\mathrm{CC}} \\ & \text { LED1 to } \mathrm{LED} 3=\mathrm{V}_{\mathrm{CC}} \\ & \text { A0 to } \mathrm{H} 0=0 \mathrm{~V} \\ & \text { A1 to } \mathrm{H} 1=\text { floating } \\ & \text { LEDx_0 }=0 \mathrm{~V} \\ & \text { LEDx1 }=\text { floating } \\ & \text { SEL }=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{IOFF}_{(\mathrm{SEL})}$ | SEL pin leakage current | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V} \\ & \mathrm{SEL}=0 \text { to } 3.6 \mathrm{~V} \end{aligned}$ | - | - | $\pm 1$ | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\mathrm{ON}}$ | Switch ON resistance ${ }^{(2)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=1.5 \text { to } \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{IN}}=-10 \text { to }-30 \mathrm{~mA} \end{aligned}$ | - | 4.0 | 6.5 | $\Omega$ |
| $\mathrm{R}_{\text {FLat }}$ | ON resistance flatness (2) (3) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}} \text { at } 1.5 \text { and } \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{IN}}=-10 \text { to }-30 \mathrm{~mA} \end{aligned}$ | - | 0.5 | - | $\Omega$ |
| $\Delta \mathrm{R}_{\mathrm{ON}}$ | ON resistance match between channel $\begin{aligned} & \Delta \mathrm{R}_{\mathrm{ON}}=\mathrm{R}_{\mathrm{ONMAX}}- \\ & \mathrm{R}_{\mathrm{ONMIN}}{ }^{(2)(4)} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}=1.5 \text { to } \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{IN}}=-10 \text { to }-30 \mathrm{~mA} \end{aligned}$ | - | 0.4 | 1 | $\Omega$ |

1. Refer to Figure 4: Test circuit for leakage current (IOFF) on page 11
2. Measured by voltage drop between channels at indicated current through the switch. ON resistance is determinate by the lower of the two voltages.
3. Flatness is defined as the difference between the $R_{\text {ONMAX }}$ and $R_{\text {ONMIN }}$ of $O N$ resistance over the specified range.
4. $\Delta R_{\mathrm{ON}}$ measured at same $\mathrm{V}_{\mathrm{CC}}$, temperature and voltage level.

Table 9. Capacitance ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{C}_{\text {IN }}$ | SEL pin input capacitance ${ }^{(1)}$ | $\begin{aligned} & D C=0.25 \mathrm{~V} \\ & A C=0.5 \mathrm{~V} P \mathrm{P} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 2 | 3 | pF |
| $\mathrm{C}_{\text {OFF }}$ | Switch off capacitance ${ }^{(2)}$ | $\begin{aligned} & \mathrm{DC}=0.25 \mathrm{~V} \\ & \mathrm{AC}=0.5 \mathrm{~V} P \mathrm{P} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 4 | 5 | pF |
| $\mathrm{CoN}_{\text {O }}$ | Switch on capacitance ${ }^{(3)}$ | $\begin{aligned} & D C=0.25 \mathrm{~V} \\ & A C=0.5 \mathrm{~V} P \mathrm{P} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 9.5 | 11 | pF |

1. Refer to Figure 5 on page 12
2. Refer to Figure 6 on page 12
3. Refer to Figure 7 on page 13

Table 10. Power supply characteristics

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent power supply | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \\ & \mathrm{GND} \end{aligned}$ | - | 150 | 500 | $\mu \mathrm{A}$ |

Table 11. Dynamic electrical characteristics ( $\mathrm{V}_{\mathrm{Cc}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -40 to $85{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{X}_{\text {talk }}$ | Crosstalk ${ }^{(1)}$ | $\begin{aligned} & R_{L}=100 \Omega \\ & \mathrm{f}=250 \mathrm{MHz} \end{aligned}$ | - | -45 | - | dB |
| $\mathrm{O}_{\text {IRR }}$ | Off isolation ${ }^{(2)}$ | $\begin{aligned} & R_{L}=100 \Omega \\ & f=250 \mathrm{MHz} \end{aligned}$ | - | -37 | - | dB |
| BW | -3 dB bandwidth ${ }^{(3)}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=100 \Omega \\ & 0<\mathrm{V}_{\mathrm{IN}} \leq 3.6 \mathrm{~V} \end{aligned}$ | - | 600 | - | MHz |

1. Refer to Figure 9 on page 14
2. Refer to Figure 10 on page 15
3. Refer to Figure 8 on page 13

Table 12. Switching characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{C}}=3.3 \mathrm{~V} \pm 10 \%$ )

| Symbol | Parameter | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max |  |
| $\mathrm{t}_{\text {PD }}$ | Propagation delay | $\mathrm{V}_{C C}=3$ to 3.6 V | - | 0.25 | - | ns |
| $\begin{aligned} & \mathrm{t}_{\mathrm{PZH}}, \\ & \mathrm{t}_{\mathrm{PZL}} \end{aligned}$ | Line enable time, SE to x to x 0 or x to x 1 | $\mathrm{V}_{\mathrm{CC}}=3$ to 3.6 V | 0.5 | 6.5 | 15 | ns |
| $\begin{gathered} \mathrm{t}_{\mathrm{PHZ}} \\ \mathrm{t}_{\mathrm{PLLZ}} \end{gathered}$ | Line disable time, SE to x to x 0 or x to x 1 | $\mathrm{V}_{C C}=3$ to 3.6 V | 0.5 | 6.5 | 8.5 | ns |
| $\mathrm{t}_{\text {SK(0) }}$ | Output skew between center port to any other port | $\mathrm{V}_{\mathrm{CC}}=3$ to 3.6 V | - | 0.1 | 0.2 | ns |
| $\mathrm{t}_{\text {SK(P) }}$ | Skew between opposite transition of the same output ( $\mathrm{t}_{\text {PHL }}, \mathrm{t}_{\mathrm{PLH}}$ ) | $\mathrm{V}_{C C}=3$ to 3.6 V | - | 0.1 | 0.2 | ns |

Table 13. ESD performance

| Symbol | Test condition | Value |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max |  |
| ESD | Contact discharge ${ }^{(1)}$ IEC61000-4-2 | - | $\pm 8$ | - | kV |
|  | Human body model (MIL-STD-883) | - | $\pm 15$ | - | kV |

1. Refer to Figure 3: Diagram for suggested VDD decoupling on page 11.

Figure 3. Diagram for suggested $\mathrm{V}_{\mathrm{DD}}$ decoupling


1. Applicable for system level ESD test

Figure 4. Test circuit for leakage current (IOFF)


Figure 5. Test circuit for SEL pin input capacitance ( $\mathrm{C}_{\mathrm{IN}}$ )


Figure 6. Test circuit for switch off capacitance (COFF)


Figure 7. Test circuit for switch on capacitance ( $\mathrm{C}_{\mathrm{ON}}$ )


Figure 8. Test circuit for bandwidth measurement (BW)


NOTE A: $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Frequency response is measured at the output of the ON channel. For example, when $\mathrm{V}_{\text {SEL }}=0$ and A is the input, the output is measured at AO . All unused analog I/O ports are left open.

HP8753ES setup:
Average $=4$
$R_{B W}=3 \mathrm{kHz}$
$\mathrm{V}_{\mathrm{BIAS}}=0.35 \mathrm{~V}$
$\mathrm{ST}=2 \mathrm{~s}$
P1 $=0 \mathrm{dBm}$

Figure 9. Test circuit for crosstalk measurement ( $\mathrm{x}_{\text {talk }}$ )


NOTES: A. $C_{L}$ includes probe and jig capacitance.
B. A $50-\Omega$ termination resistor is needed to match the loading of the network analyzer.

Crosstalk is measured at the output of the non-adjacent ON channel. For example, when $V_{\text {SEL }}=0$, and $B$ is the input, the output is measured at $D$. All unused analog input ports are connected to GND and output ports are left open.
HP8753ES setup:
Average $=4$
$\mathrm{R}_{\mathrm{BW}}=3 \mathrm{kHz}$
$\mathrm{V}_{\mathrm{BIAS}}=0.35 \mathrm{~V}$
$\mathrm{ST}=2 \mathrm{~s}$
$\mathrm{P} 1=0 \mathrm{dBm}$

Figure 10. Test circuit for off isolation measurement ( $\mathrm{O}_{\text {IRR }}$ )


NOTES: $\mathrm{A} . \mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.
B. A $50-\Omega$ termination resistor is needed to match the loading of the network analyzer.

Off isolation is measured at the output of the OFF channel. For example, when $\mathrm{V}_{\text {SEL }}=0$, and $B$ is the input, the output is measured at B1. All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup:
Average $=4$
$\mathrm{R}_{\mathrm{BW}}=3 \mathrm{kHz}$
$\mathrm{V}_{\mathrm{BIAS}}=0.35 \mathrm{~V}$
ST $=2 \mathrm{~s}$
$\mathrm{P} 1=0 \mathrm{dBm}$

## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK ${ }^{\circledR}$ packages, depending on their level of environmental compliance. ECOPACK ${ }^{\circledR}$ specifications, grade definitions and product status are available at: www.st.com. ECOPACK ${ }^{\circledR}$ is an ST trademark.

Figure 11. Package outline for QFN56 (11 x 5 mm ) pitch 0.5 mm



Figure 12. Mechanical data for QFN56 (11 x 5 mm ) pitch 0.5 mm

| Symbol | Millimeters |  |  |
| :---: | :---: | :---: | :---: |
|  | Min | Typ | Max |
| A | 0.70 | 0.75 | 0.80 |
| A1 | - | - | 0.05 |
| A3 |  | 0.20 | - |
| b | 0.20 | 0.25 | 0.30 |
| D | 10.90 | 11.00 | 11.10 |
| D2 | - | 8.30 | 9.50 |
| D3 | 4.90 | 5.00 | - |
| E | 2.30 | 2.40 | 5.10 |
| E2 | - | 3.50 | 2.50 |
| E3 | - | 0.50 | - |
| e | 0.30 | 0.40 | - |
| L |  |  | 0.50 |

Figure 13. Footprint recommendation for QFN56 (11 x 5 mm ) pitch 0.5 mm


Figure 14. Carrier tape information for QFN56 (11 x 5 mm ) pitch 0.5 mm


Figure 15. Reel information for QFN56 (11 x 5 mm ) pitch 0.5 mm


## 5 Revision history

Table 14. Document revision history

| Date | Revision | Changes |
| :---: | :---: | :--- |
| 26-Feb-2008 | 1 | Initial release. |
| 24-Sep-2008 | 2 | Modified: datasheet title, channel on capacitance value from 7.5 pF <br> to 9.5 pF typical, Figure 1, Table 2, Section 3: Electrical <br> characteristics. <br> Added: fields of applications, Table 6 and QFN56 footprint <br> recommendations in Figure 13 on page 17. |
| 30-Mar-2009 | 3 | Updated: Features section, Table 5 on page 6, Table 11 on page 9 <br> and Table 13 on page 10 and Chapter 4: Package mechanical data. |
| 22-Jun-2009 | 4 | Document promoted from Preliminary data to datasheet. |

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